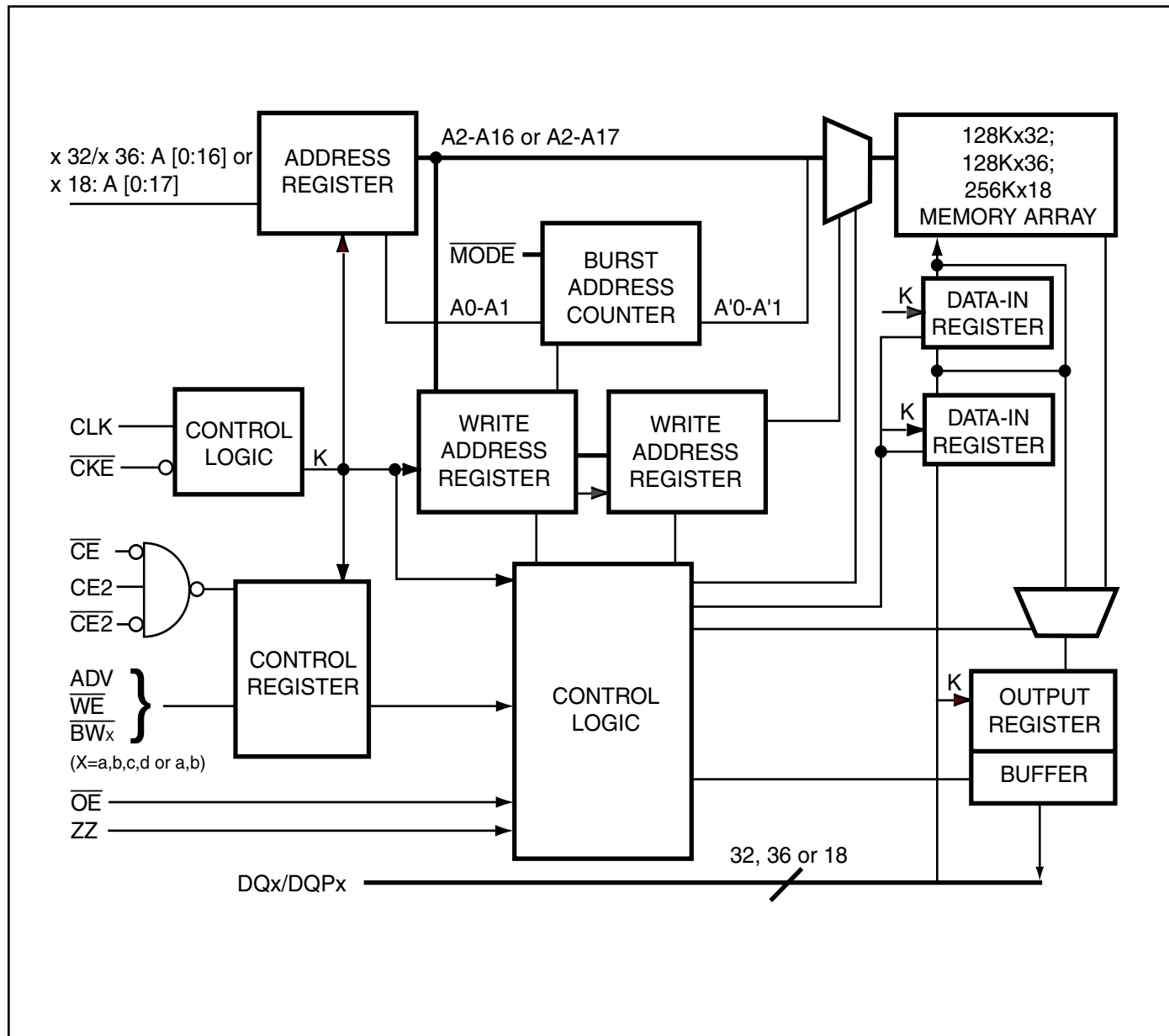
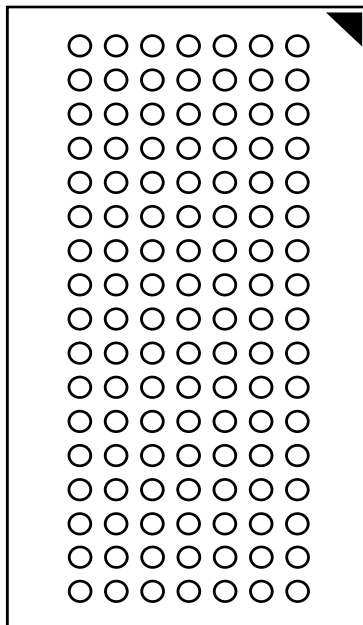
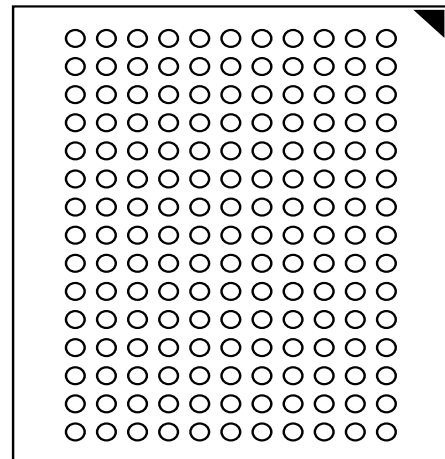


BLOCK DIAGRAM





Bottom View
119-Ball, 14 mm x 22 mm BGA
1 mm Ball Pitch, 7 x 17 Ball Array



Bottom View
165-Ball, 13 mm x 15mm BGA
1 mm Ball Pitch, 11 x 15 Ball Array

PIN CONFIGURATION — 128K x 36, 165-Ball PBGA (TOP VIEW)

	1	2	3	4	5	6	7	8	9	10	11
A	NC	A	\overline{CE}	\overline{BWc}	\overline{BWb}	$\overline{CE2}$	\overline{CKE}	ADV	NC	A	NC
B	NC	A	CE2	\overline{BWd}	\overline{BWa}	CLK	\overline{WE}	\overline{OE}	NC	A	NC
C	DQPc	NC	V _{DDQ}	V _{SS}	V _{SS}	V _{SS}	V _{SS}	V _{SS}	V _{DDQ}	NC	DQPb
D	DQc	DQc	V _{DDQ}	V _{DD}	V _{SS}	V _{SS}	V _{SS}	V _{DD}	V _{DDQ}	DQb	DQb
E	DQc	DQc	V _{DDQ}	V _{DD}	V _{SS}	V _{SS}	V _{SS}	V _{DD}	V _{DDQ}	DQb	DQb
F	DQc	DQc	V _{DDQ}	V _{DD}	V _{SS}	V _{SS}	V _{SS}	V _{DD}	V _{DDQ}	DQb	DQb
G	DQc	DQc	V _{DDQ}	V _{DD}	V _{SS}	V _{SS}	V _{SS}	V _{DD}	V _{DDQ}	DQb	DQb
H	NC	NC	NC	V _{DD}	V _{SS}	V _{SS}	V _{SS}	V _{DD}	NC	NC	ZZ
J	DQd	DQd	V _{DDQ}	V _{DD}	V _{SS}	V _{SS}	V _{SS}	V _{DD}	V _{DDQ}	DQa	DQa
K	DQd	DQd	V _{DDQ}	V _{DD}	V _{SS}	V _{SS}	V _{SS}	V _{DD}	V _{DDQ}	DQa	DQa
L	DQd	DQd	V _{DDQ}	V _{DD}	V _{SS}	V _{SS}	V _{SS}	V _{DD}	V _{DDQ}	DQa	DQa
M	DQd	DQd	V _{DDQ}	V _{DD}	V _{SS}	V _{SS}	V _{SS}	V _{DD}	V _{DDQ}	DQa	DQa
N	DQPd	NC	V _{DDQ}	V _{SS}	NC	NC	NC	V _{SS}	V _{DDQ}	NC	DQPa
P	NC	NC	A	A	NC	A1*	NC	A	A	A	NC
R	MODE	NC	A	A	NC	A0*	NC	A	A	A	A

Note: A0 and A1 are the two least significant bits (LSB) of the address field and set the internal burst counter if burst is desired.

PIN DESCRIPTIONS

Symbol	Pin Name
A	Address Inputs
A0, A1	Synchronous Burst Address Inputs
ADV	Synchronous Burst Address Advance/Load
\overline{WE}	Synchronous Read/Write Control Input
CLK	Synchronous Clock
\overline{CKE}	Clock Enable
\overline{CE} , $\overline{CE2}$, CE2	Synchronous Chip Enable
\overline{BWx} (x=a-d)	Synchronous Byte Write Inputs
\overline{OE}	Output Enable
ZZ	Power Sleep Mode

MODE	Burst Sequence Selection
V _{DD}	3.3V/2.5V Power Supply
NC	No Connect
DQx	Data Inputs/Outputs
DQP _x	Parity Data I/O
V _{DDQ}	Isolated output Power Supply 3.3V/2.5V
V _{SS}	Ground

119-PIN PBGA PACKAGE CONFIGURATION —128K x 36 (TOP VIEW)

	1	2	3	4	5	6	7
A	V _{DDQ}	A	A	NC	A	A	V _{DDQ}
B	NC	CE2	A	ADV	A	$\overline{\text{CE2}}$	NC
C	NC	A	A	V _{DD}	A	A	NC
D	DQc	DQPc	V _{SS}	NC	V _{SS}	DQPb	DQb
E	DQc	DQc	V _{SS}	$\overline{\text{CE}}$	V _{SS}	DQb	DQb
F	V _{DDQ}	DQc	V _{SS}	$\overline{\text{OE}}$	V _{SS}	DQb	V _{DDQ}
G	DQc	DQc	$\overline{\text{BWc}}$	NC	$\overline{\text{BWb}}$	DQb	DQb
H	DQc	DQc	V _{SS}	$\overline{\text{WE}}$	V _{SS}	DQb	DQb
J	V _{DDQ}	V _{DD}	NC	V _{DD}	NC	V _{DD}	V _{DDQ}
K	DQd	DQd	V _{SS}	CLK	V _{SS}	DQa	DQa
L	DQd	DQd	$\overline{\text{BWd}}$	NC	$\overline{\text{BWa}}$	DQa	DQa
M	V _{DDQ}	DQd	V _{SS}	$\overline{\text{CKE}}$	V _{SS}	DQa	V _{DDQ}
N	DQd	DQd	V _{SS}	A ₁ *	V _{SS}	DQa	DQa
P	DQd	DQPd	V _{SS}	A ₀ *	V _{SS}	DQPa	DQa
R	NC	A	MODE	V _{DD}	NC	A	NC
T	NC	NC	A	A	A	NC	ZZ
U	V _{DDQ}	NC	NC	NC	NC	NC	V _{DDQ}

Note: A0 and A1 are the two least significant bits(LSB) of the address field and set the internal burst counter if burst is desired.

PIN DESCRIPTIONS

Symbol	Pin Name
A	Address Inputs
A0, A1	Synchronous Burst Address Inputs
ADV	Synchronous Burst Address Advance/Load
$\overline{\text{WE}}$	Synchronous Read/Write Control Input
CLK	Synchronous Clock
$\overline{\text{CKE}}$	Clock Enable
$\overline{\text{CE}}$	Synchronous Chip Select
$\overline{\text{CE2}}$	Synchronous Chip Select
CE2	Synchronous Chip Select
$\overline{\text{BWx}}$ (x=a-d)	Synchronous Byte Write Inputs

$\overline{\text{OE}}$	Output Enable
ZZ	Power Sleep Mode
MODE	Burst Sequence Selection
V _{DD}	Power Supply
V _{SS}	Ground
NC	No Connect
DQa-DQd	Data Inputs/Outputs
DQPa-Pd	Parity Data I/O
V _{DDQ}	Output Power Supply

165-PIN PBGA PACKAGE CONFIGURATION —256K x 18 (TOP VIEW)

	1	2	3	4	5	6	7	8	9	10	11
A	NC	A	\overline{CE}	\overline{BWb}	NC	$\overline{CE2}$	\overline{CKE}	ADV	NC	A	A
B	NC	A	CE2	NC	\overline{BWa}	CLK	\overline{WE}	\overline{OE}	NC	A	NC
C	NC	NC	VDDQ	Vss	Vss	Vss	Vss	Vss	VDDQ	NC	DQPa
D	NC	DQb	VDDQ	VDD	Vss	Vss	Vss	VDD	VDDQ	NC	DQa
E	NC	DQb	VDDQ	VDD	Vss	Vss	Vss	VDD	VDDQ	NC	DQa
F	NC	DQb	VDDQ	VDD	Vss	Vss	Vss	VDD	VDDQ	NC	DQa
G	NC	DQb	VDDQ	VDD	Vss	Vss	Vss	VDD	VDDQ	NC	DQa
H	NC	NC	NC	VDD	Vss	Vss	Vss	VDD	NC	NC	ZZ
J	DQb	NC	VDDQ	VDD	Vss	Vss	Vss	VDD	VDDQ	DQa	NC
K	DQb	NC	VDDQ	VDD	Vss	Vss	Vss	VDD	VDDQ	DQa	NC
L	DQb	NC	VDDQ	VDD	Vss	Vss	Vss	VDD	VDDQ	DQa	NC
M	DQb	NC	VDDQ	VDD	Vss	Vss	Vss	VDD	VDDQ	DQa	NC
N	DQPb	NC	VDDQ	Vss	NC	NC	NC	Vss	VDDQ	NC	NC
P	NC	NC	A	A	NC	A ₁ *	NC	A	A	A	NC
R	MODE	NC	A	A	NC	A ₀ *	NC	A	A	A	A

Note: A0 and A1 are the two least significant bits (LSB) of the address field and set the internal burst counter if burst is desired.

PIN DESCRIPTIONS

Symbol	Pin Name
A	Address Inputs
A0, A1	Synchronous Burst Address Inputs
ADV	Synchronous Burst Address Advance/Load
\overline{WE}	Synchronous Read/Write Control Input
CLK	Synchronous Clock
\overline{CKE}	Clock Enable
\overline{CE} , $\overline{CE2}$, CE2	Synchronous Chip Enable
\overline{BWx} (x=a,b)	Synchronous Byte Write Inputs
\overline{OE}	Output Enable
ZZ	Power Sleep Mode

MODE	Burst Sequence Selection
VDD	3.3V/2.5V Power Supply
NC	No Connect
DQx	Data Inputs/Outputs
DQPx	Parity Data I/O
VDDQ	Isolated output Power Supply 3.3V/2.5V
Vss	Ground

119-PIN PBGA PACKAGE CONFIGURATION —256K x 18 (TOP VIEW)

	1	2	3	4	5	6	7
A	VDDQ	A	A	NC	A	A	VDDQ
B	NC	CE2	A	ADV	A	$\overline{\text{CE}}2$	NC
C	NC	A	A	VDD	A	A	NC
D	DQb	NC	Vss	NC	Vss	DQPa	NC
E	NC	DQb	Vss	$\overline{\text{CE}}$	Vss	NC	DQa
F	VDDQ	NC	Vss	$\overline{\text{OE}}$	Vss	DQa	VDDQ
G	NC	DQb	$\overline{\text{BW}}b$	NC	NC	NC	DQa
H	DQb	NC	Vss	$\overline{\text{WE}}$	Vss	DQa	NC
J	VDDQ	VDD	NC	VDD	NC	VDD	VDDQ
K	NC	DQb	Vss	CLK	Vss	NC	DQa
L	DQb	NC	NC	NC	$\overline{\text{BW}}a$	DQa	NC
M	VDDQ	DQb	Vss	$\overline{\text{CKE}}$	Vss	NC	VDDQ
N	DQb	NC	Vss	A1*	Vss	DQa	NC
P	NC	DQPb	Vss	A0*	Vss	NC	DQa
R	NC	A	MODE	VDD	NC	A	NC
T	NC	A	A	NC	A	A	ZZ
U	VDDQ	NC	NC	NC	NC	NC	VDDQ

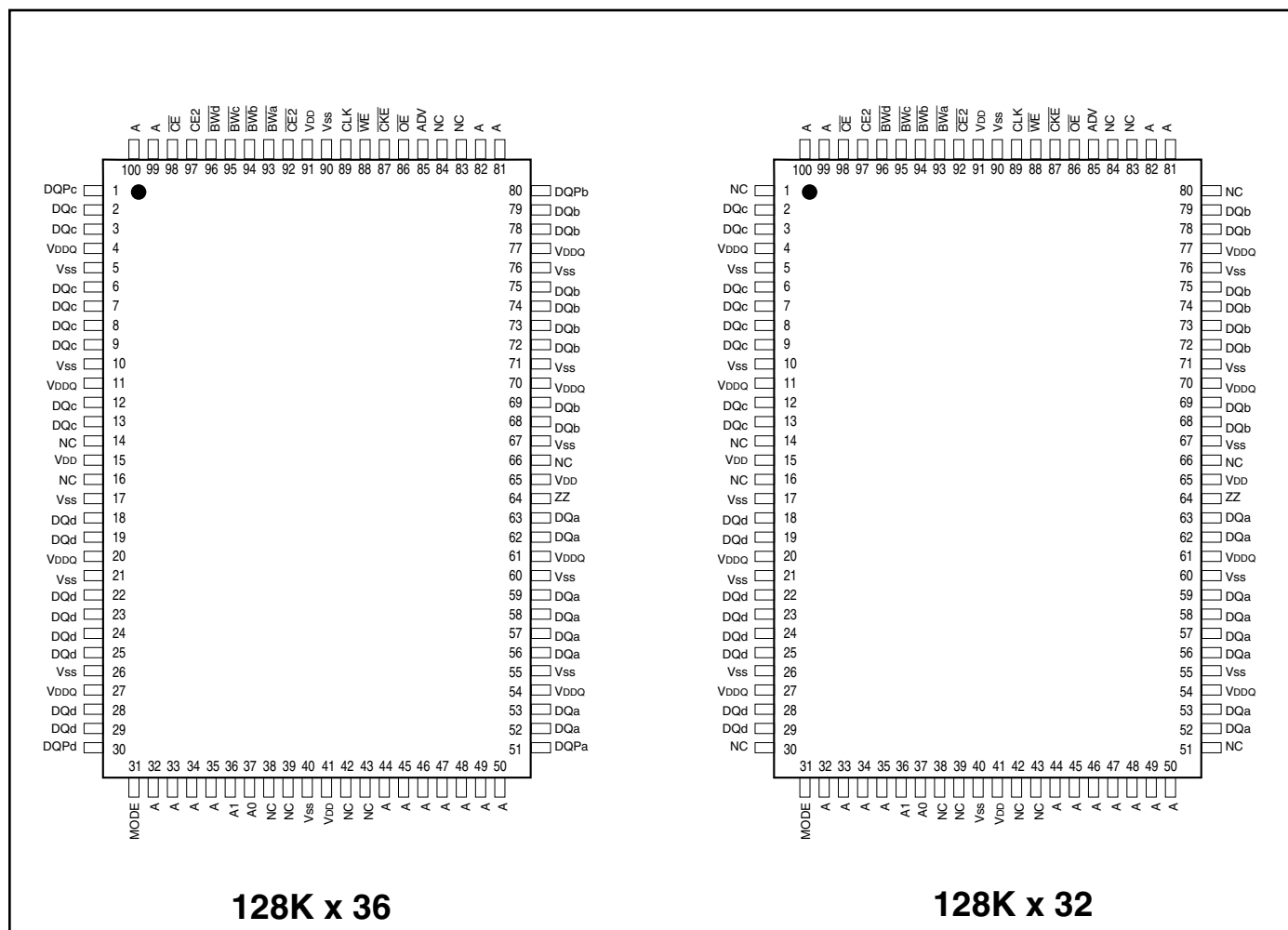
Note: A0 and A1 are the two least significant bits(LSB) of the address field and set the internal burst counter if burst is desired.

PIN DESCRIPTIONS

Symbol	Pin Name
A	Address Inputs
A0, A1	Synchronous Burst Address Inputs
ADV	Synchronous Burst Address Advance/Load
$\overline{\text{WE}}$	Synchronous Read/Write Control Input
CLK	Synchronous Clock
$\overline{\text{CKE}}$	Clock Enable
$\overline{\text{CE}}$	Synchronous Chip Select
$\overline{\text{CE}}2$	Synchronous Chip Select
CE2	Synchronous Chip Select
$\overline{\text{BW}}x$ (x=a,b)	Synchronous Byte Write Inputs

$\overline{\text{OE}}$	Output Enable
ZZ	Power Sleep Mode
MODE	Burst Sequence Selection
VDD	Power Supply
Vss	Ground
NC	No Connect
DQa-DQb	Data Inputs/Outputs
DQPa-Pb	Parity Data I/O
VDDQ	Output Power Supply

100-Pin TQFP



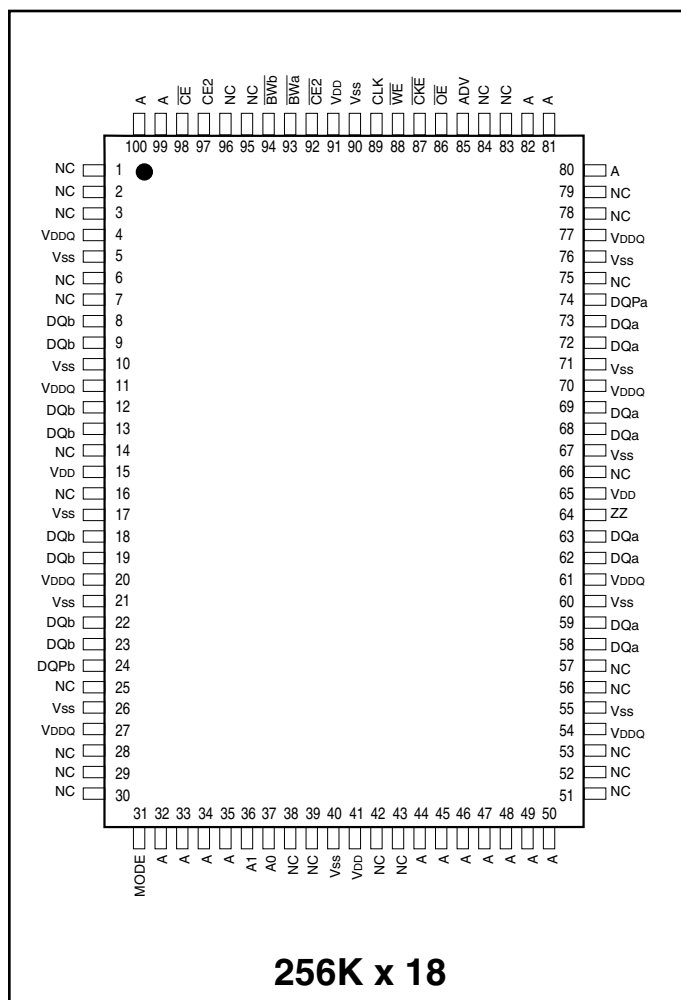
PIN DESCRIPTIONS

A0, A1	Synchronous Address Inputs. These pins must tied to the two LSBs of the address bus.
A	Synchronous Address Inputs
CLK	Synchronous Clock
ADV	Synchronous Burst Address Advance
\overline{BWA} - \overline{BWD}	Synchronous Byte Write Enable
\overline{WE}	Write Enable
\overline{CKE}	Clock Enable
Vss	Ground for Core
NC	Not Connected

$\overline{\text{CE}}$, CE2 , $\overline{\text{CE2}}$	Synchronous Chip Enable
$\overline{\text{OE}}$	Output Enable
DQa-DQd	Synchronous Data Input/Output
DQPa-DQPd	Parity Data I/O
MODE	Burst Sequence Selection
V _{DD}	+3.3V/2.5V Power Supply
V _{SS}	Ground for output Buffer
V _{DDQ}	Isolated Output Buffer Supply: +3.3V/2.5V
ZZ	Snooze Enable

PIN CONFIGURATION

100-Pin TQFP

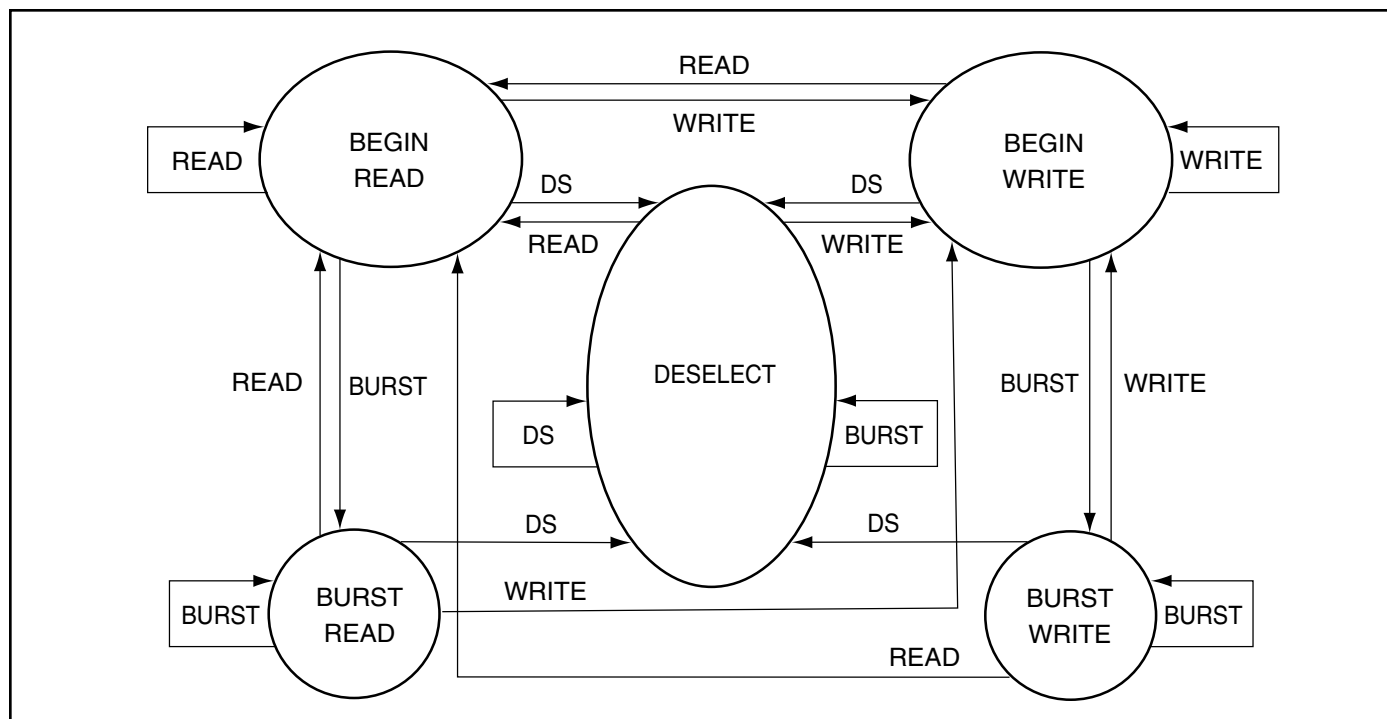


PIN DESCRIPTIONS

A0, A1	Synchronous Address Inputs. These pins must tied to the two LSBs of the address bus.
A	Synchronous Address Inputs
CLK	Synchronous Clock
ADV	Synchronous Burst Address Advance
BW \bar{a} -BW \bar{d}	Synchronous Byte Write Enable
WE	Write Enable
CKE	Clock Enable
Vss	Ground for Core
NC	Not Connected

CE, CE2, CE2	Synchronous Chip Enable
OE	Output Enable
DQa-DQd	Synchronous Data Input/Output
DQPa-DQPd	Parity Data I/O
MODE	Burst Sequence Selection
VDD	+3.3V/2.5V Power Supply
Vss	Ground for output Buffer
VDDQ	Isolated Output Buffer Supply: +3.3V/2.5V
ZZ	Snooze Enable

STATE DIAGRAM



SYNCHRONOUS TRUTH TABLE⁽¹⁾

Operation	Address Used	\overline{CE}	CE2	$\overline{CE2}$	ADV	\overline{WE}	$\overline{BW_x}$	\overline{OE}	\overline{CKE}	CLK
Not Selected	N/A	H	X	X	L	X	X	X	L	↑
Not Selected	N/A	X	L	X	L	X	X	X	L	↑
Not Selected	N/A	X	X	H	L	X	X	X	L	↑
Not Selected Continue	N/A	X	X	X	H	X	X	X	L	↑
Begin Burst Read	External Address	L	H	L	L	H	X	L	L	↑
Continue Burst Read	Next Address	X	X	X	H	X	X	L	L	↑
NOP/Dummy Read	External Address	L	H	L	L	H	X	H	L	↑
Dummy Read	Next Address	X	X	X	H	X	X	H	L	↑
Begin Burst Write	External Address	L	H	L	L	L	L	X	L	↑
Continue Burst Write	Next Address	X	X	X	H	X	L	X	L	↑
NOP/Write Abort	N/A	L	H	L	L	L	H	X	L	↑
Write Abort	Next Address	X	X	X	H	X	H	X	L	↑
Ignore Clock	Current Address	X	X	X	X	X	X	X	H	↑

Notes:

- "X" means don't care.
- The rising edge of clock is symbolized by ↑
- A continue deselect cycle can only be entered if a deselect cycle is executed first.
- $\overline{WE} = L$ means Write operation in Write Truth Table.
 $\overline{WE} = H$ means Read operation in Write Truth Table.
- Operation finally depends on status of asynchronous pins (ZZ and \overline{OE}).

ASYNCHRONOUS TRUTH TABLE⁽¹⁾

Operation	ZZ	\overline{OE}	I/O STATUS
Sleep Mode	H	X	High-Z
Read	L	L	DQ
	L	H	High-Z
Write	L	X	Din, High-Z
Deselected	L	X	High-Z

Notes:

1. X means "Don't Care".
2. For write cycles following read cycles, the output buffers must be disabled with \overline{OE} , otherwise data bus contention will occur.
3. Sleep Mode means power Sleep Mode where stand-by current does not depend on cycle time.
4. Deselected means power Sleep Mode where stand-by current depends on cycle time.

WRITE TRUTH TABLE (x18)

Operation	\overline{WE}	\overline{BWa}	\overline{BWb}
READ	H	X	X
WRITE BYTE a	L	L	H
WRITE BYTE b	L	H	L
WRITE ALL BYTES	L	L	L
WRITE ABORT/NOP	L	H	H

Notes:

1. X means "Don't Care".
2. All inputs in this table must meet setup and hold time around the rising edge of CLK.

WRITE TRUTH TABLE (x32/x36)

Operation	\overline{WE}	\overline{BWa}	\overline{BWb}	\overline{BWc}	\overline{BWd}
READ	H	X	X	X	X
WRITE BYTE a	L	L	H	H	H
WRITE BYTE b	L	H	L	H	H
WRITE BYTE c	L	H	H	L	H
WRITE BYTE d	L	H	H	H	L
WRITE ALL BYTES	L	L	L	L	L
WRITE ABORT/NOP	L	H	H	H	H

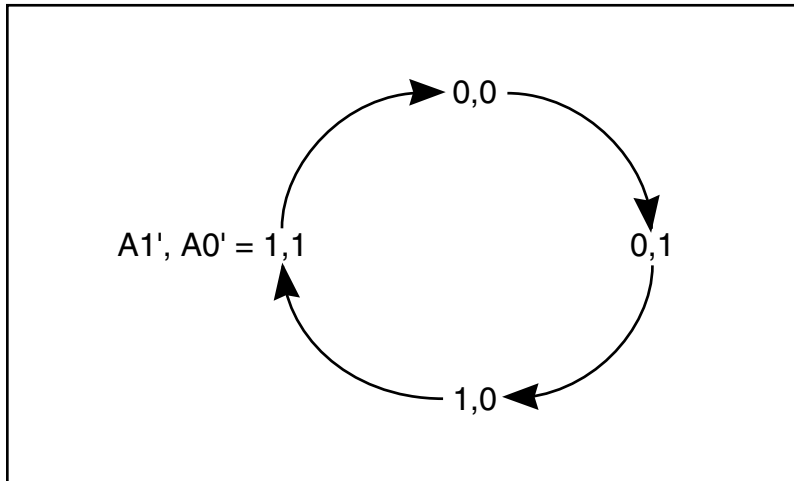
Notes:

1. X means "Don't Care".
2. All inputs in this table must meet setup and hold time around the rising edge of CLK.

INTERLEAVED BURST ADDRESS TABLE (MODE = V_{DD} or NC)

External Address A1 A0	1st Burst Address A1 A0	2nd Burst Address A1 A0	3rd Burst Address A1 A0
00	01	10	11
01	00	11	10
10	11	00	01
11	10	01	00

LINEAR BURST ADDRESS TABLE (MODE = V_{SS})



ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Parameter	Value	Unit
T _{STG}	Storage Temperature	−65 to +150	°C
P _D	Power Dissipation	1.6	W
I _{OUT}	Output Current (per I/O)	100	mA
V _{IN} , V _{OUT}	Voltage Relative to V _{SS} for I/O Pins	−0.5 to V _{DDQ} + 0.5	V
V _{IN}	Voltage Relative to V _{SS} for for Address and Control Inputs	−0.5 to 4.6	V

Notes:

1. Stress greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
2. This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields; however, precautions may be taken to avoid application of any voltage higher than maximum rated voltages to this high-impedance circuit.
3. This device contains circuitry that will ensure the output devices are in High-Z at power up.

OPERATING RANGE (IS61NLPx)

Range	Ambient Temperature	V _{DD}	V _{DDQ}
Commercial	0°C to +70°C	3.3V ± 5%	3.3V / 2.5V ± 5%
Industrial	−40°C to +85°C	3.3V ± 5%	3.3V / 2.5V ± 5%

OPERATING RANGE (IS61NVPx)

Range	Ambient Temperature	V _{DD}	V _{DDQ}
Commercial	0°C to +70°C	2.5V ± 5%	2.5V ± 5%
Industrial	−40°C to +85°C	2.5V ± 5%	2.5V ± 5%

DC ELECTRICAL CHARACTERISTICS (Over Operating Range)

Symbol	Parameter	Test Conditions	3.3V		2.5V		Unit
			Min.	Max.	Min.	Max.	
V _{OH}	Output HIGH Voltage	I _{OH} = -4.0 mA (3.3V) I _{OH} = -1.0 mA (2.5V)	2.4	—	2.0	—	V
V _{OL}	Output LOW Voltage	I _{OL} = 8.0 mA (3.3V) I _{OL} = 1.0 mA (2.5V)	—	0.4	—	0.4	V
V _{IH} ⁽¹⁾	Input HIGH Voltage		2.0	V _{DD} + 0.3	1.7	V _{DD} + 0.3	V
V _{IL} ⁽¹⁾	Input LOW Voltage		-0.3	0.8	-0.3	0.7	V
I _{LI}	Input Leakage Current	V _{SS} ≤ V _{IN} ≤ V _{DD} ⁽¹⁾	-5	5	-5	5	μA
I _{LO}	Output Leakage Current	V _{SS} ≤ V _{OUT} ≤ V _{DDQ} , \overline{OE} = V _{IH}	-5	5	-5	5	μA

Note:

1. Overshoot: V_{IH} (AC) < V_{DD} + 2.0V (Pulse width less than t_{kc}/2). Undershoot: V_{IL} (AC) > -2V (Pulse width less than t_{kc}/2).

POWER SUPPLY CHARACTERISTICS⁽¹⁾ (Over Operating Range)

Symbol	Parameter	Test Conditions	Temp. range	-250 MAX		-200 MAX		Unit
				x18	x32/x36	x18	x32/x36	
I _{CC}	AC Operating Supply Current	Device Selected, \overline{OE} = V _{IH} , ZZ ≤ V _{IL} , All Inputs ≤ 0.2V or ≥ V _{DD} - 0.2V, Cycle Time ≥ t _{kc} min.	Com. Ind.	225 250	225 250	200 210	200 210	mA
I _{SB}	Standby Current TTL Input	Device Deselected, V _{DD} = Max., All Inputs ≤ V _{IL} or ≥ V _{IH} , ZZ ≤ V _{IL} , f = Max.	Com. Ind.	90 100	90 100	90 100	90 100	mA
I _{SBI}	Standby Current CMOS Input	Device Deselected, V _{DD} = Max., V _{IN} ≤ V _{SS} + 0.2V or ≥ V _{DD} - 0.2V f = 0	Com. Ind. typ. ⁽²⁾	70 75 40	70 75	70 75	70 75	mA
I _{SB2}	Sleep Mode	ZZ > V _{IH}	Com. Ind. typ. ⁽²⁾	30 35 20	30 35	30 35	30 35	mA

Note:

1. MODE pin has an internal pullup and should be tied to V_{DD} or V_{SS}. It exhibits ±100μA maximum leakage current when tied to ≤ V_{SS} + 0.2V or ≥ V_{DD} - 0.2V.
2. Typical values are measured at V_{DD} = 3.3V, T_A = 25°C and not 100% tested.

CAPACITANCE^(1,2)

Symbol	Parameter	Conditions	Max.	Unit
C _{IN}	Input Capacitance	V _{IN} = 0V	6	pF
C _{OUT}	Input/Output Capacitance	V _{OUT} = 0V	8	pF

Notes:

1. Tested initially and after any design or process changes that may affect these parameters.
2. Test conditions: T_A = 25°C, f = 1 MHz, V_{DD} = 3.3V.

3.3V I/O AC TEST CONDITIONS

Parameter	Unit
Input Pulse Level	0V to 3.0V
Input Rise and Fall Times	1.5 ns
Input and Output Timing and Reference Level	1.5V
Output Load	See Figures 1 and 2

3.3V I/O OUTPUT LOAD EQUIVALENT

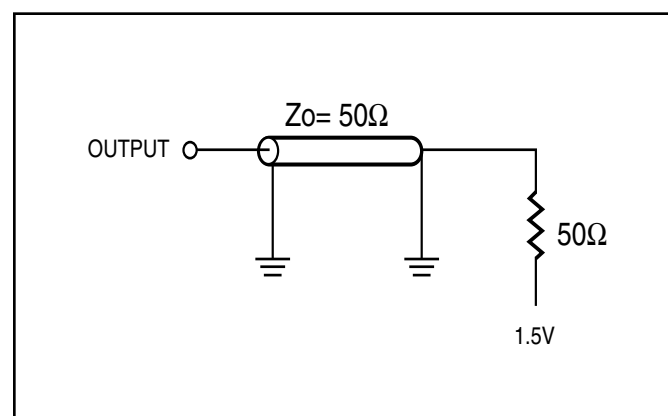


Figure 1

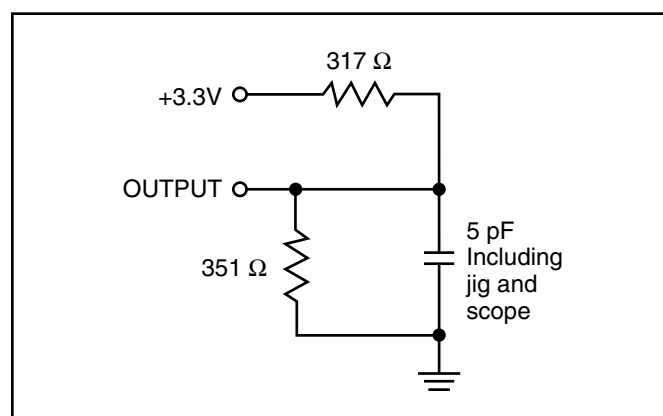


Figure 2

2.5V I/O AC TEST CONDITIONS

Parameter	Unit
Input Pulse Level	0V to 2.5V
Input Rise and Fall Times	1.5 ns
Input and Output Timing and Reference Level	1.25V
Output Load	See Figures 3 and 4

2.5V I/O OUTPUT LOAD EQUIVALENT

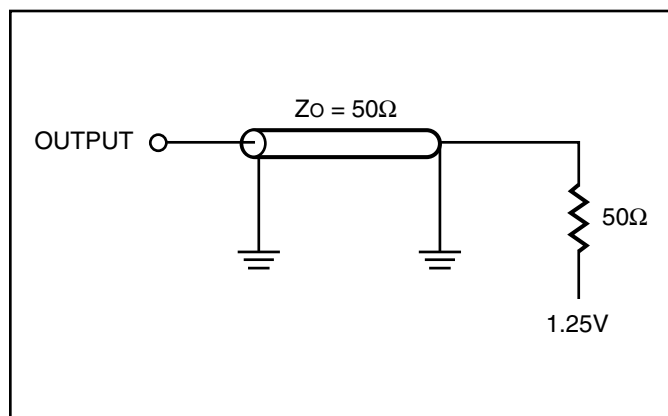


Figure 3

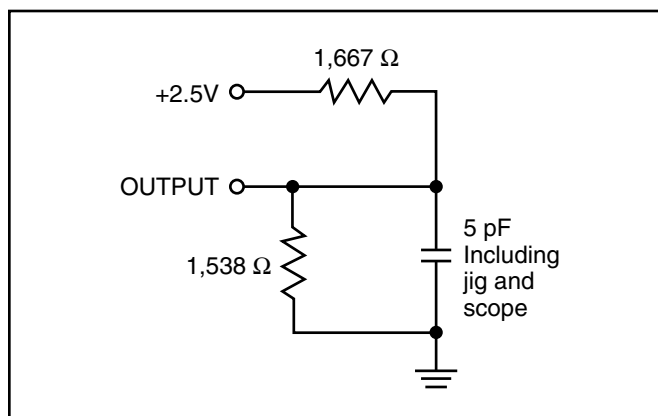


Figure 4

READ/WRITE CYCLE SWITCHING CHARACTERISTICS⁽¹⁾ (Over Operating Range)

Symbol	Parameter	-250		-200		Unit
		Min.	Max.	Min.	Max.	
fmax	Clock Frequency	—	250	—	200	MHz
t _{KC}	Cycle Time	4.0	—	5	—	ns
t _{KH}	Clock High Time	1.7	—	2	—	ns
t _{KL}	Clock Low Time	1.7	—	2	—	ns
t _{KQ}	Clock Access Time	—	2.6	—	3.1	ns
t _{KQX} ⁽²⁾	Clock High to Output Invalid	0.8	—	1.5	—	ns
t _{KQLZ} ^(2,3)	Clock High to Output Low-Z	0.8	—	1	—	ns
t _{KQHZ} ^(2,3)	Clock High to Output High-Z	—	2.6	—	3.0	ns
t _{OEQ}	Output Enable to Output Valid	—	2.8	—	3.1	ns
t _{OELZ} ^(2,3)	Output Enable to Output Low-Z	0	—	0	—	ns
t _{OEHZ} ^(2,3)	Output Disable to Output High-Z	—	2.6	—	3.0	ns
t _{AS}	Address Setup Time	1.2	—	1.4	—	ns
t _{WS}	Read/Write Setup Time	1.2	—	1.4	—	ns
t _{CES}	Chip Enable Setup Time	1.2	—	1.4	—	ns
t _{SE}	Clock Enable Setup Time	1.2	—	1.4	—	ns
t _{ADVS}	Address Advance Setup Time	1.2	—	1.4	—	ns
t _{DS}	Data Setup Time	1.2	—	1.4	—	ns
t _{AH}	Address Hold Time	0.3	—	0.4	—	ns
t _{HE}	Clock Enable Hold Time	0.3	—	0.4	—	ns
t _{WH}	Write Hold Time	0.3	—	0.4	—	ns
t _{CEH}	Chip Enable Hold Time	0.3	—	0.4	—	ns
t _{ADVH}	Address Advance Hold Time	0.3	—	0.4	—	ns
t _{DH}	Data Hold Time	0.3	—	0.4	—	ns
t _{PDS}	ZZ High to Power Down	—	2	—	2	cyc
t _{PUS}	ZZ Low to Power Down	—	2	—	2	cyc

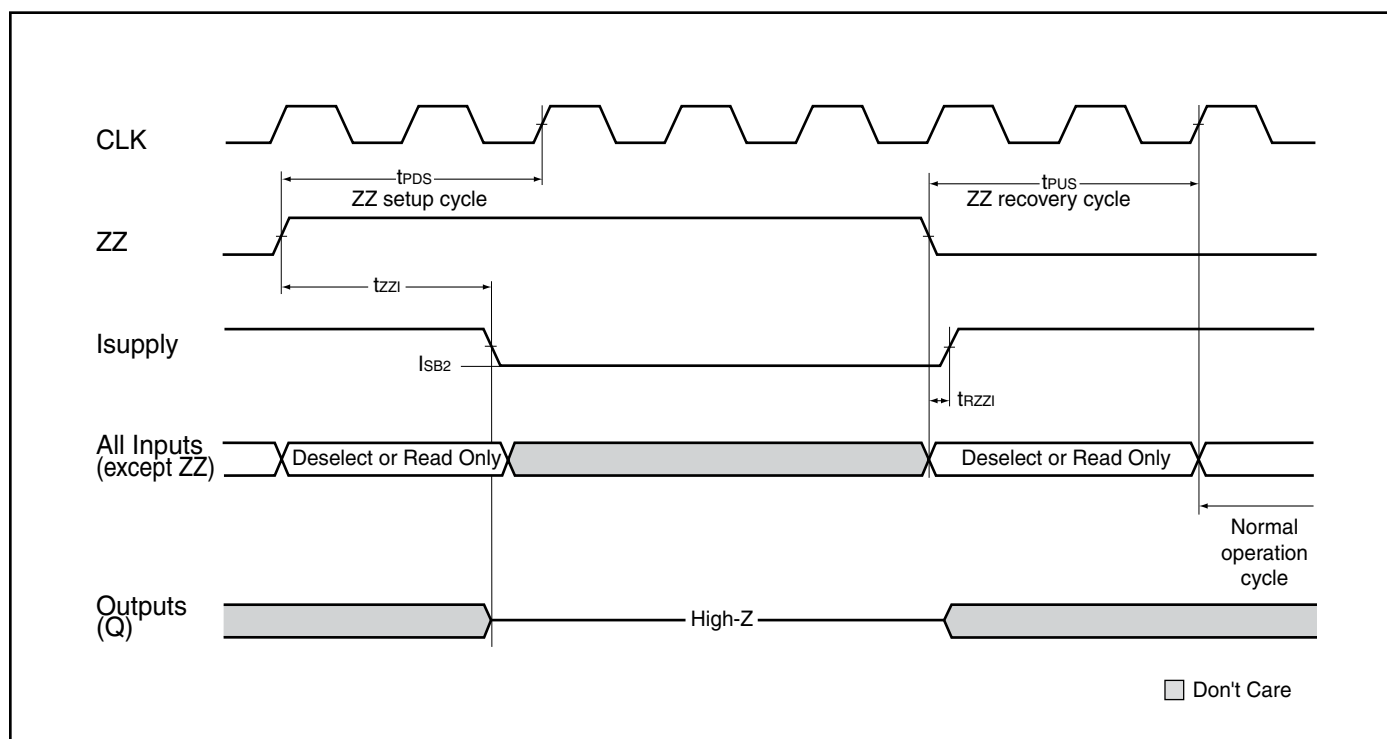
Notes:

1. Configuration signal MODE is static and must not change during normal operation.
2. Guaranteed but not 100% tested. This parameter is periodically sampled.
3. Tested with load in Figure 2.

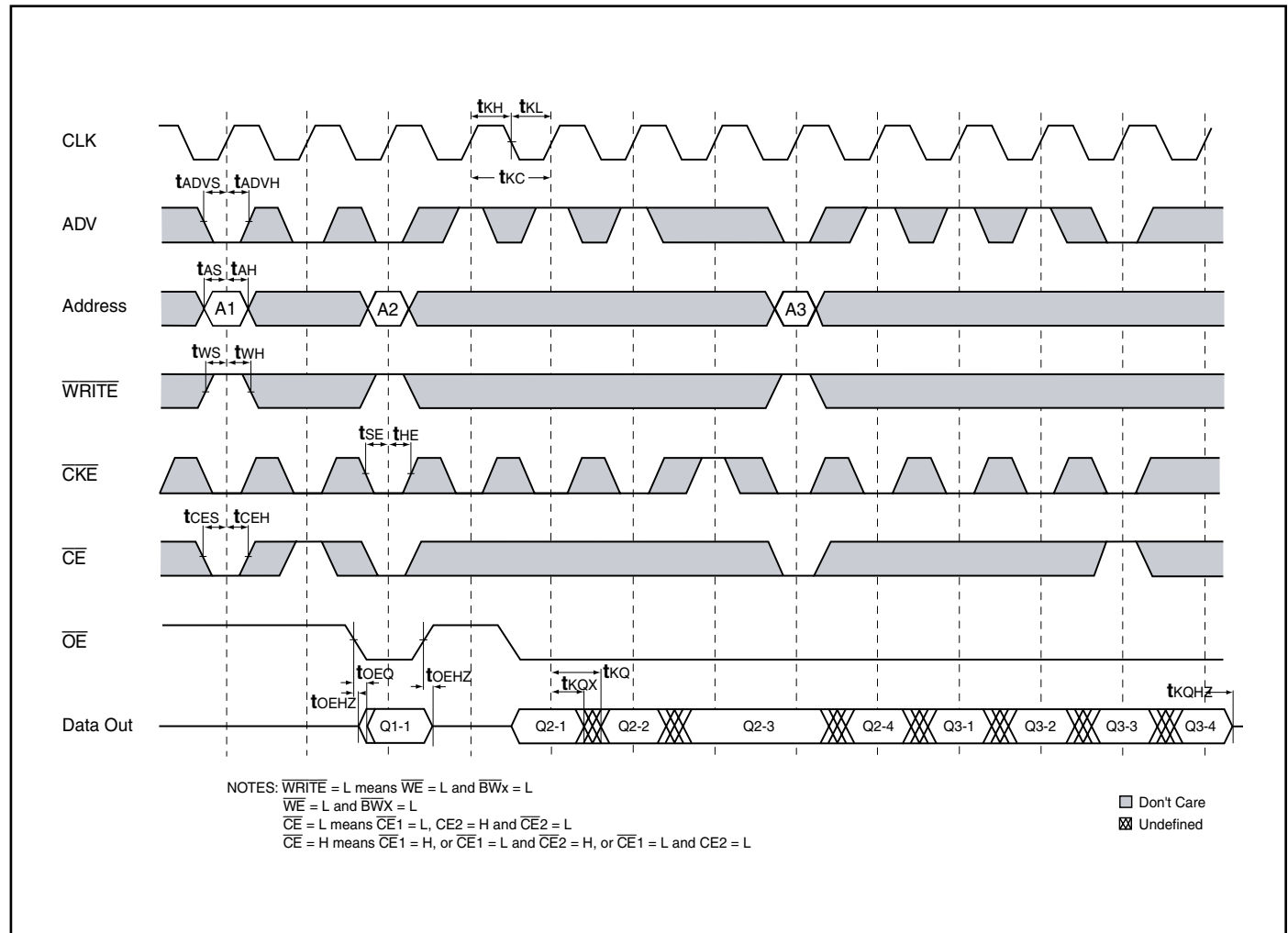
SLEEP MODE ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions	Min.	Max.	Unit
I _{SB2}	Current during SLEEP MODE	ZZ ≥ V _{IH}		35	mA
t _{PDS}	ZZ active to input ignored		2		cycle
t _{PUS}	ZZ inactive to input sampled		2		cycle
t _{ZZI}	ZZ active to SLEEP current		2		cycle
t _{trZZI}	ZZ inactive to exit SLEEP current		0		ns

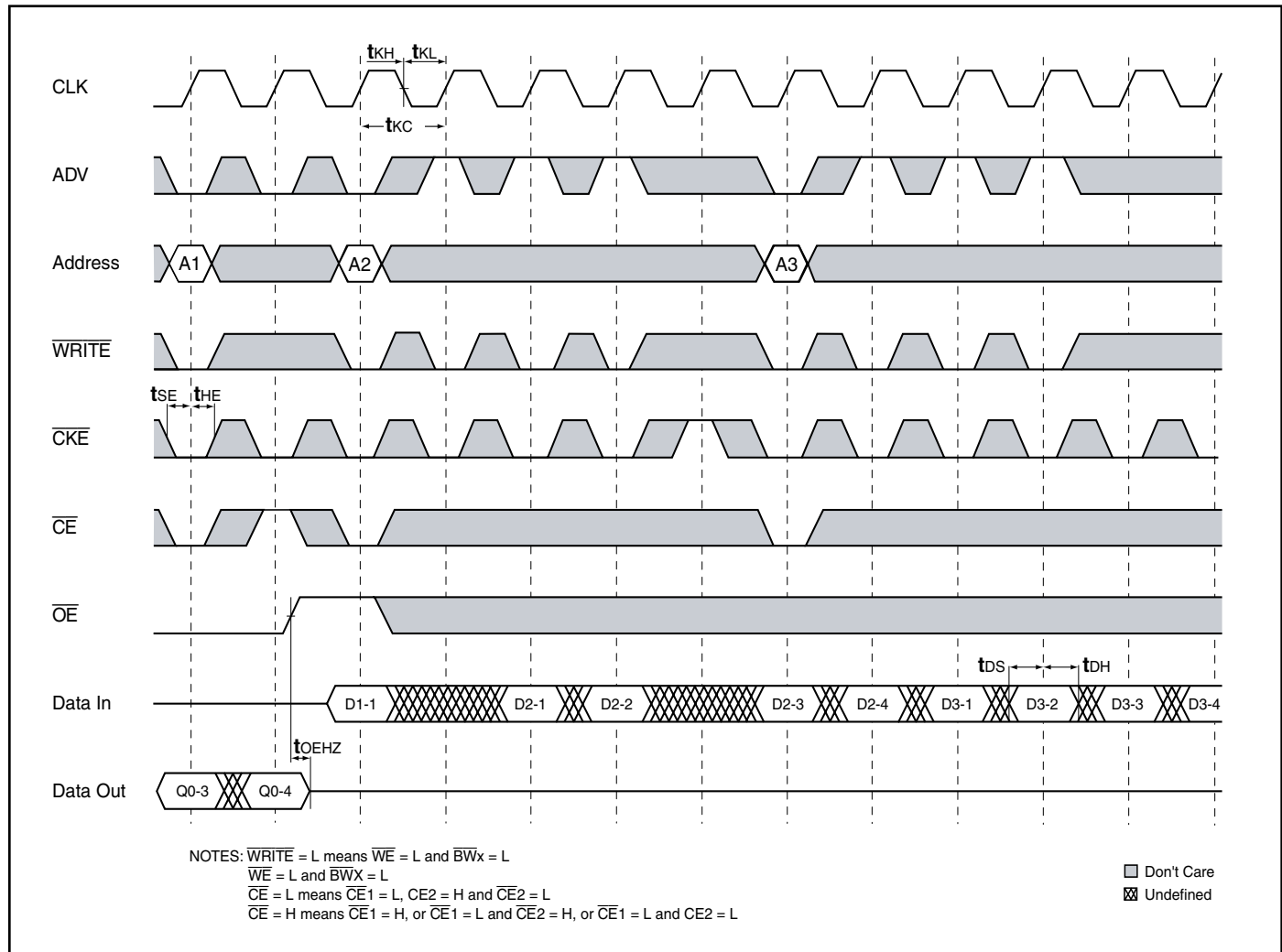
SLEEP MODE TIMING



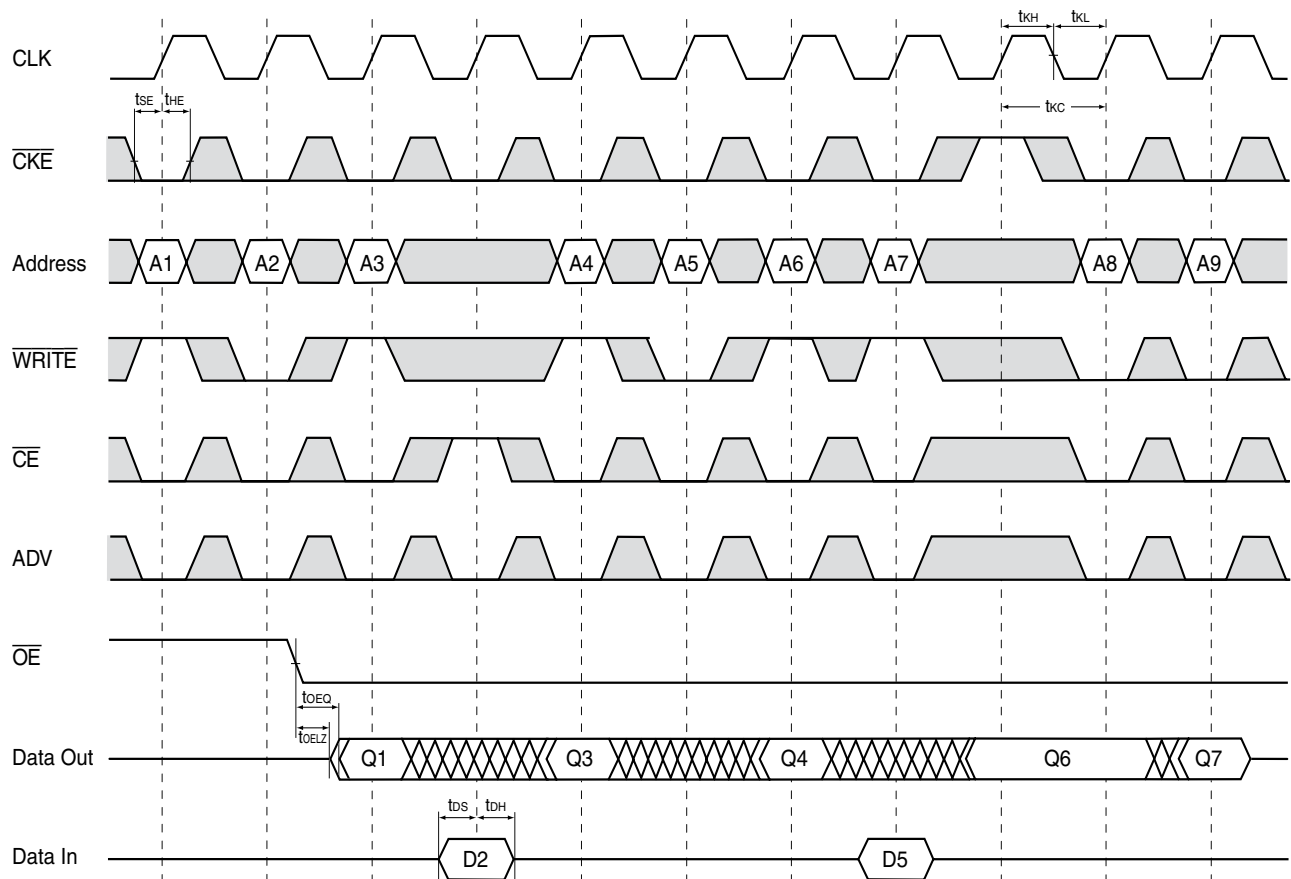
READ CYCLE TIMING



WRITE CYCLE TIMING



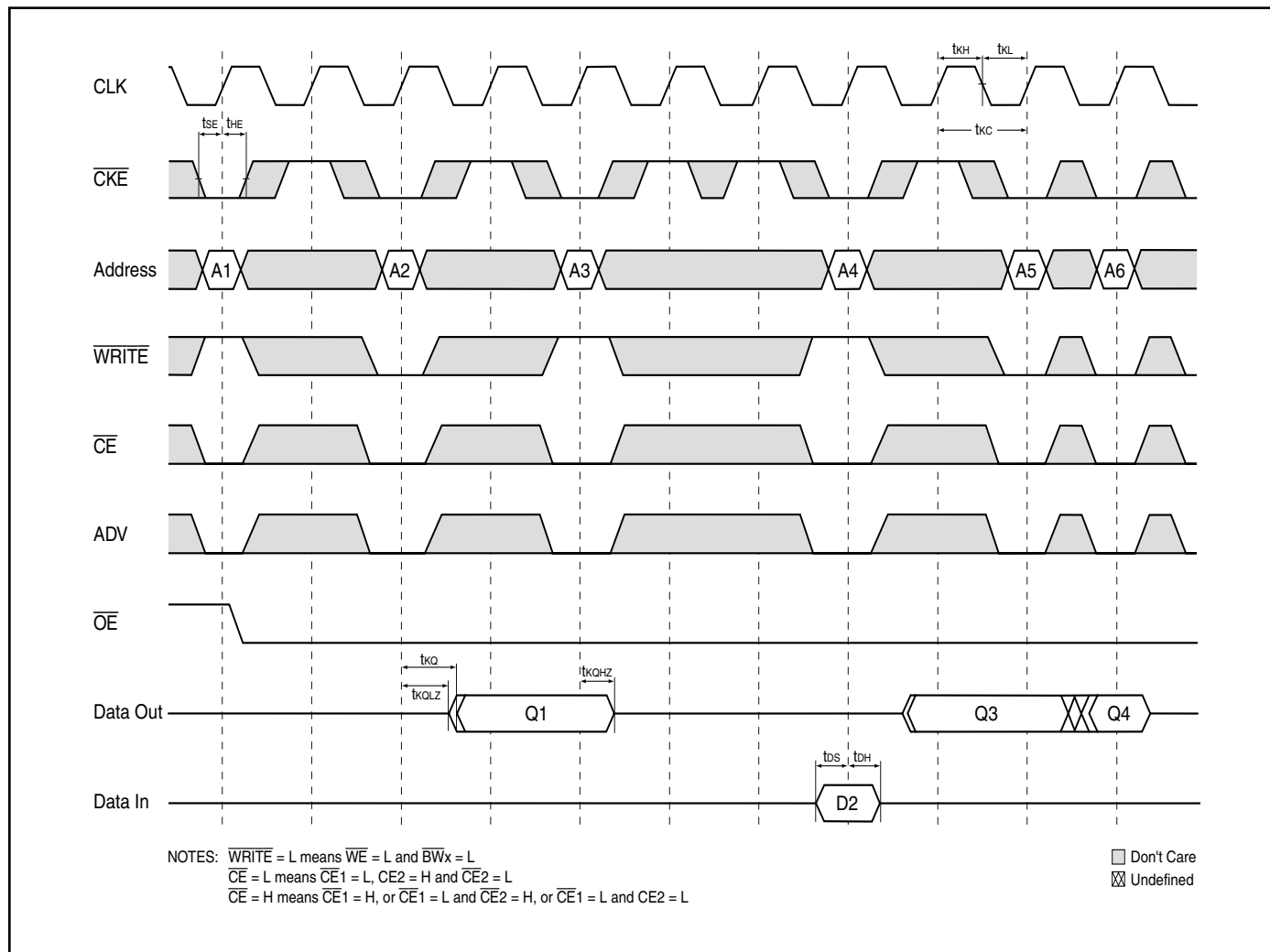
SINGLE READ/WRITE CYCLE TIMING



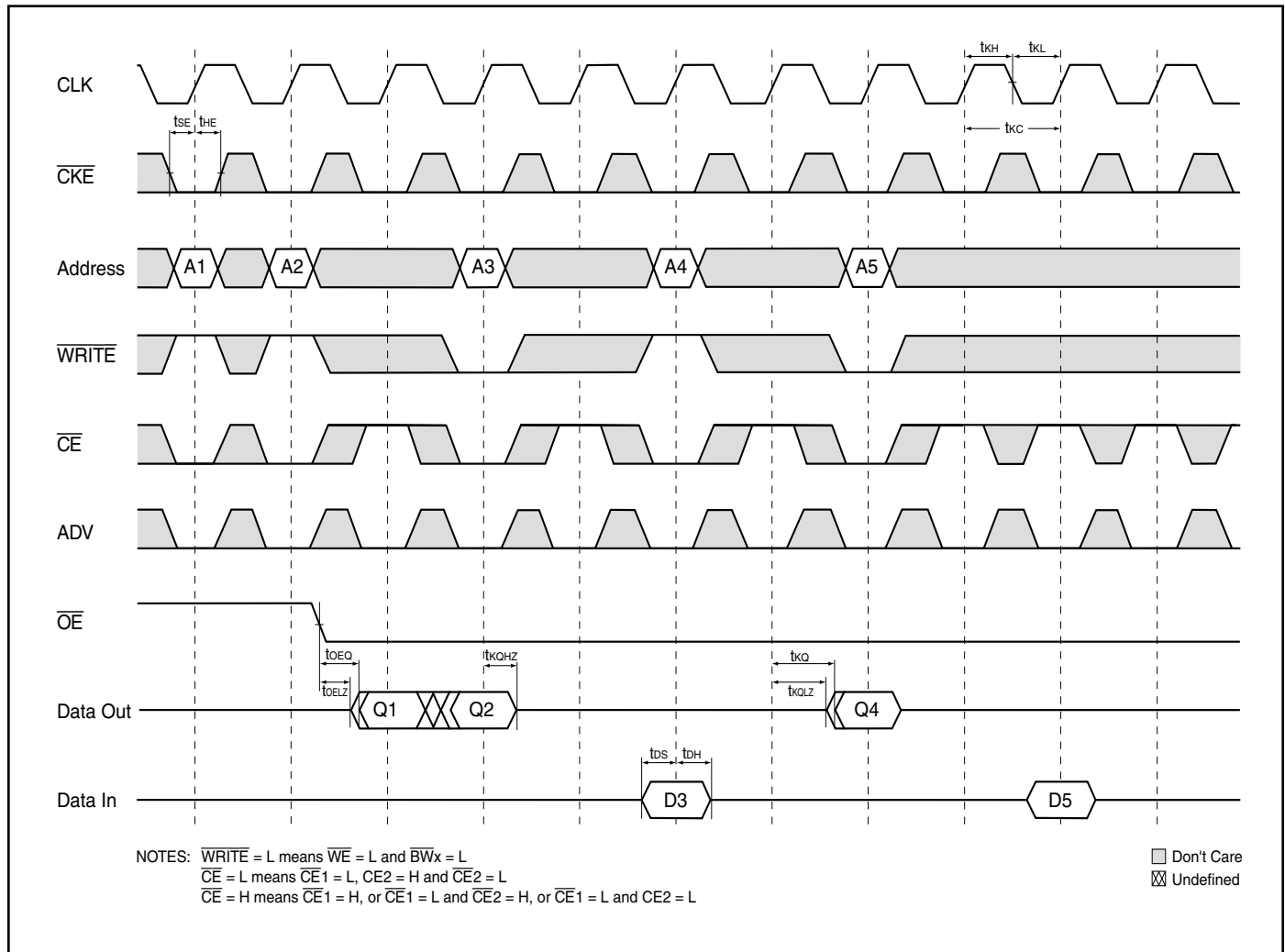
NOTES: $\overline{\text{WRITE}} = \text{L}$ means $\overline{\text{WE}} = \text{L}$ and $\overline{\text{BWx}} = \text{L}$
 $\overline{\text{CE}} = \text{L}$ means $\overline{\text{CE1}} = \text{L}$, $\overline{\text{CE2}} = \text{H}$ and $\overline{\text{CE2}} = \text{L}$
 $\overline{\text{CE}} = \text{H}$ means $\overline{\text{CE1}} = \text{H}$, or $\overline{\text{CE1}} = \text{L}$ and $\overline{\text{CE2}} = \text{H}$, or $\overline{\text{CE1}} = \text{L}$ and $\overline{\text{CE2}} = \text{L}$

□ Don't Care
 X Undefined

CKE OPERATION TIMING



CE OPERATION TIMING



ORDERING INFORMATION ($V_{DD} = 3.3V/V_{DDQ} = 2.5V/3.3V$)
Commercial Range: 0°C to +70°C

Access Time	Order Part Number	Package
128Kx32		
250	IS61NLP12832B-250TQ	100 TQFP
	IS61NLP12832B-250B3	165 PBGA
	IS61NLP12832B-250B2	119 PBGA
200	IS61NLP12832B-200TQ	100 TQFP
	IS61NLP12832B-200B3	165 PBGA
	IS61NLP12832B-200B2	119 PBGA
128Kx36		
250	IS61NLP12836B-250TQ	100 TQFP
	IS61NLP12836B-250B3	165 PBGA
	IS61NLP12836B-250B2	119 PBGA
200	IS61NLP12836B-200TQ	100 TQFP
	IS61NLP12836B-200B3	165 PBGA
	IS61NLP12836B-200B2	119 PBGA
256Kx18		
250	IS61NLP25618A-250TQ	100 TQFP
	IS61NLP25618A-250B3	165 PBGA
	IS61NLP25618A-250B2	119 PBGA
200	IS61NLP25618A-200TQ	100 TQFP
	IS61NLP25618A-200B3	165 PBGA
	IS61NLP25618A-200B2	119 PBGA

ORDERING INFORMATION ($V_{DD} = 3.3V/V_{DDQ} = 2.5V/3.3V$)

Industrial Range: -40°C to +85°C

Access Time	Order Part Number	Package
128Kx32		
250	IS61NLP12832B-250TQI	100 TQFP
	IS61NLP12832B-250B3I	165 PBGA
	IS61NLP12832B-250B2I	119 PBGA
200	IS61NLP12832B-200TQI	100 TQFP
	IS61NLP12832B-200TQLI	100 TQFP, Lead-free
	IS61NLP12832B-200B3I	165 PBGA
	IS61NLP12832B-200B2I	119 PBGA
128Kx36		
250	IS61NLP12836B-250TQI	100 TQFP
	IS61NLP12836B-250B3I	165 PBGA
	IS61NLP12836B-250B2I	119 PBGA
200	IS61NLP12836B-200TQI	100 TQFP
	IS61NLP12836B-200TQLI	100 TQFP, Lead-free
	IS61NLP12836B-200B3I	165 PBGA
	IS61NLP12836B-200B2I	119 PBGA
	IS61NLP12836B-200B2LI	119 PBGA, Lead-free
256Kx18		
250	IS61NLP25618A-250TQI	100 TQFP
	IS61NLP25618A-250B3I	165 PBGA
	IS61NLP25618A-250B2I	119 PBGA
200	IS61NLP25618A-200TQI	100 TQFP
	IS61NLP25618A-200TQLI	100 TQFP, Lead-free
	IS61NLP25618A-200B3I	165 PBGA
	IS61NLP25618A-200B3LI	165 PBGA, Lead-free
	IS61NLP25618A-200B2I	119 PBGA

ORDERING INFORMATION ($V_{DD} = 2.5V/V_{DDQ} = 2.5V$)

Commercial Range: 0°C to +70°C

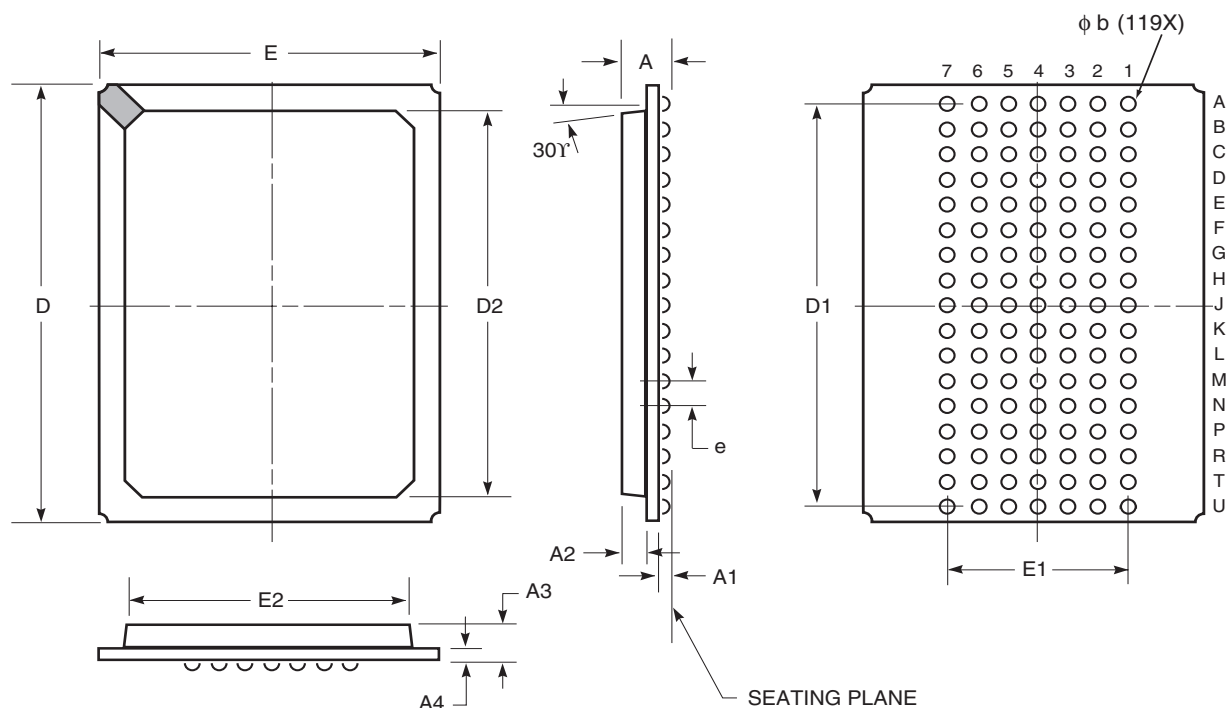
Access Time	Order Part Number	Package
128Kx36		
250	IS61NVP12836B-250TQ	100 TQFP
	IS61NVP12836B-250B3	165 PBGA
	IS61NVP12836B-250B2	119 PBGA
200	IS61NVP12836B-200TQ	100 TQFP
	IS61NVP12836B-200B3	165 PBGA
	IS61NVP12836B-200B2	119 PBGA
256Kx18		
250	IS61NVP25618A-250TQ	100 TQFP
	IS61NVP25618A-250B3	165 PBGA
	IS61NVP25618A-250B2	119 PBGA
200	IS61NVP25618A-200TQ	100 TQFP
	IS61NVP25618A-200B3	165 PBGA
	IS61NVP25618A-200B2	119 PBGA

Industrial Range: -40°C to +85°C

Access Time	Order Part Number	Package
128Kx36		
250	IS61NVP12836B-250TQI	100 TQFP
	IS61NVP12836B-250B3I	165 PBGA
	IS61NVP12836B-250B2I	119 PBGA
200	IS61NVP12836B-200TQI	100 TQFP
	IS61NVP12836B-200B3I	165 PBGA
	IS61NVP12836B-200B2I	119 PBGA
256Kx18		
250	IS61NVP25618A-250TQI	100 TQFP
	IS61NVP25618A-250B3I	165 PBGA
	IS61NVP25618A-250B2I	119 PBGA
200	IS61NVP25618A-200TQI	100 TQFP
	IS61NVP25618A-200B3I	165 PBGA
	IS61NVP25618A-200B2I	119 PBGA

PACKAGING INFORMATION

Plastic Ball Grid Array

Package Code: B (119-pin)

MILLIMETERS			INCHES	
Sym.	Min.	Max.	Min.	Max.
N0. Leads	119			
A	—	2.41	—	0.095
A1	0.50	0.70	0.020	0.028
A2	0.80	1.00	0.032	0.039
A3	1.30	1.70	0.051	0.067
A4	0.56 BSC		0.022 BSC	
b	0.60	0.90	0.024	0.035
D	21.80	22.20	0.858	0.874
D1	20.32 BSC		0.800 BSC	
D2	19.40	19.60	0.764	0.772
E	13.80	14.20	0.543	0.559
E1	7.62 BSC		0.300 BSC	
E2	11.90	12.10	0.469	0.476
e	1.27 BSC		0.050 BSC	

Notes:

1. Controlling dimension: millimeters, unless otherwise specified.
2. BSC = Basic lead spacing between centers.
3. Dimensions D1 and E do not include mold flash protrusion and should be measured from the bottom of the package.
4. Formed leads shall be planar with respect to one another within 0.004 inches at the seating plane.

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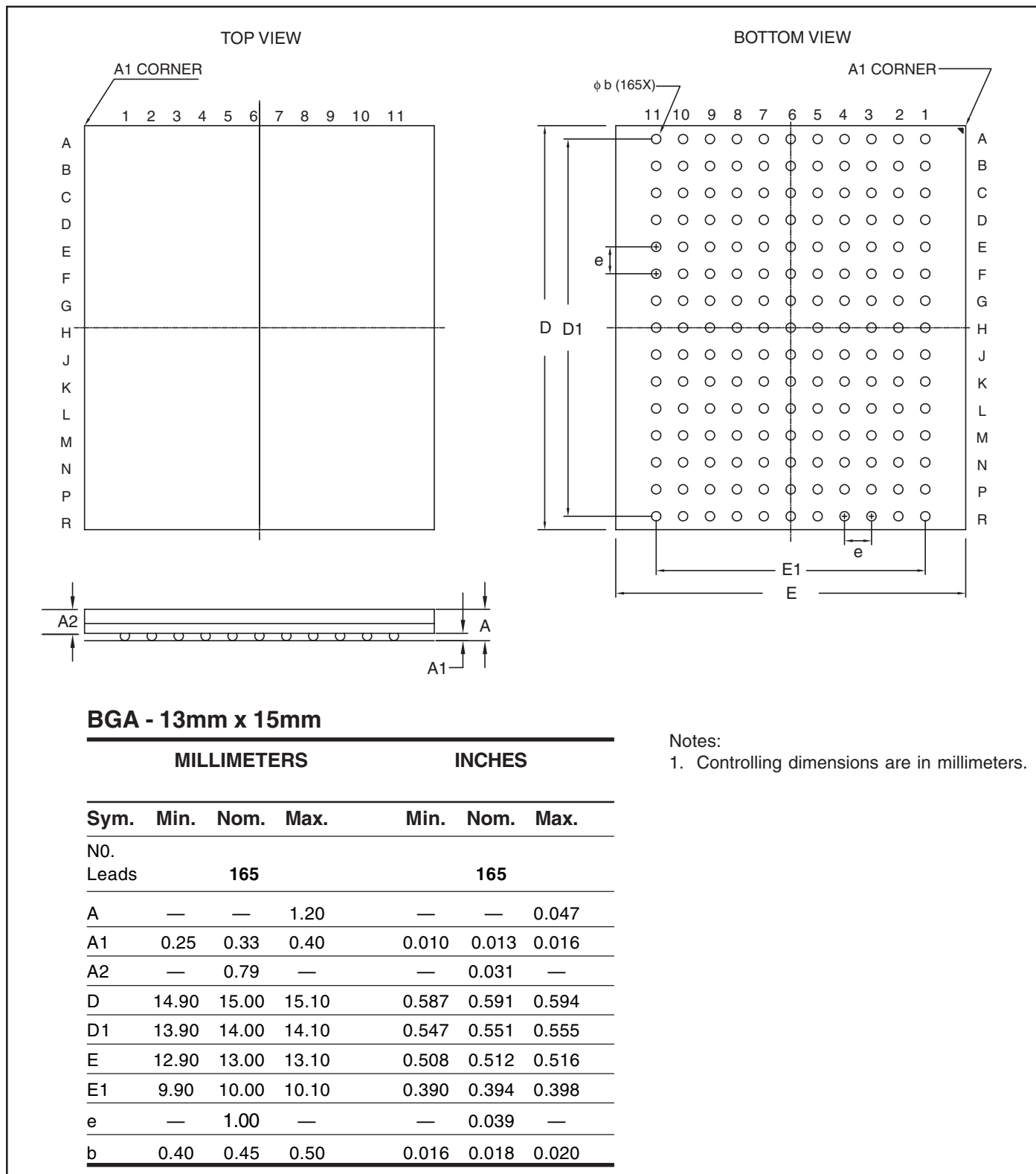
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Rev. B
02/12/03

PACKAGING INFORMATION

Ball Grid Array

Package Code: B (165-pin)



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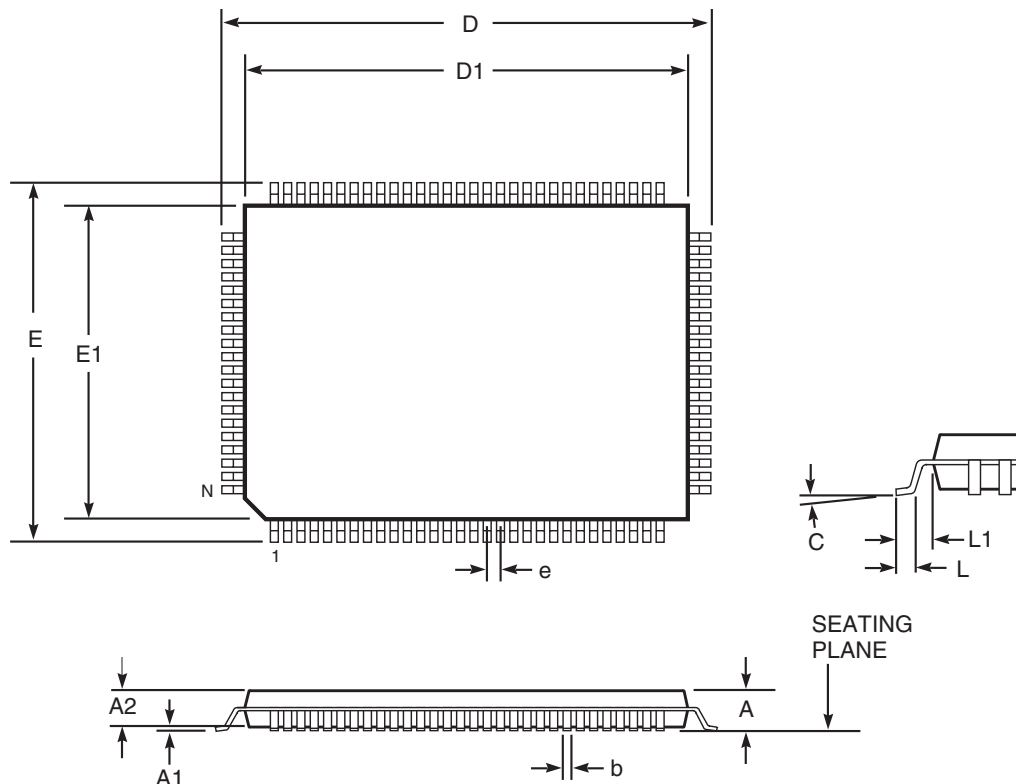
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Rev. A
06/11/03

PACKAGING INFORMATION

TQFP (Thin Quad Flat Pack Package)

Package Code: TQ



Thin Quad Flat Pack (TQ)								
Symbol	Millimeters		Inches					
	Min	Max	Min	Max	Min	Max	Min	Max
Ref. Std.								
No. Leads	(N)	100			128			
A	—	1.60	—	0.063	—	1.60	—	0.063
A1	0.05	0.15	0.002	0.006	0.05	0.15	0.002	0.006
A2	1.35	1.45	0.053	0.057	1.35	1.45	0.053	0.057
b	0.22	0.38	0.009	0.015	0.17	0.27	0.007	0.011
D	21.90	22.10	0.862	0.870	21.80	22.20	0.858	0.874
D1	19.90	20.10	0.783	0.791	19.90	20.10	0.783	0.791
E	15.90	16.10	0.626	0.634	15.80	16.20	0.622	0.638
E1	13.90	14.10	0.547	0.555	13.90	14.10	0.547	0.555
e	0.65 BSC		0.026 BSC		0.50 BSC		0.020 BSC	
L	0.45	0.75	0.018	0.030	0.45	0.75	0.018	0.030
L1	1.00 REF.		0.039 REF.		1.00 REF.		0.039 REF.	
C	0°	7°	0°	7°	0°	7°	0°	7°

Notes:

1. All dimensioning and tolerancing conforms to ANSI Y14.5M-1982.
2. Dimensions D1 and E1 do not include mold protrusions. Allowable protrusion is 0.25 mm per side. D1 and E1 do include mold mismatch and are determined at datum plane -H-.
3. Controlling dimension: millimeters.